



**TAYCHIPST**

**HIGH EFFICIENCY RECTIFIER**

**ERB32-01 THRU ERB32-02**

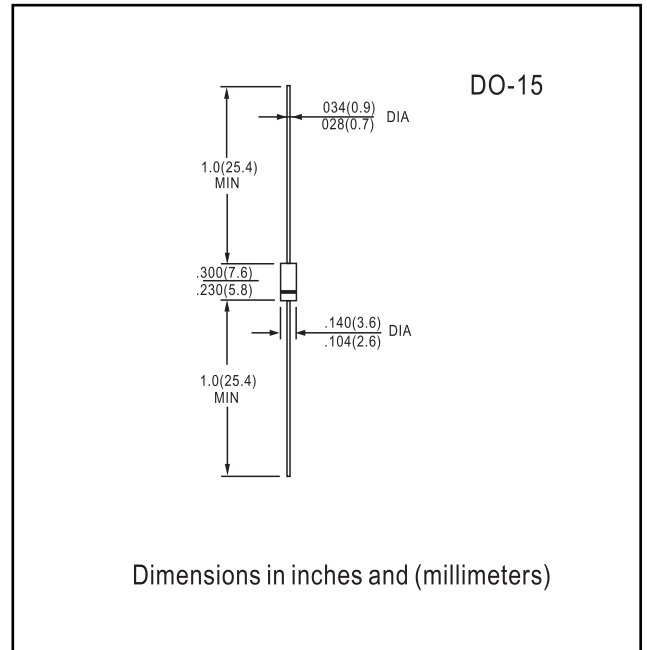
**100V-200V 1.2A**

**FEATURES**

- Low cost
- Diffused junction
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with Freon,Alcohol,Isopropanol and similar solvents
- The plastic material carries U/L recognition 94V-0

**MECHANICAL DATA**

Case:JEDEC DO--15,molded plastic  
 Terminals: Axial lead ,solderable per MIL- STD-202,Method 208  
 Polarity: Color band denotes cathode  
 Weight: 0.014 ounces,0.39 grams  
 Mounting position: Any



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

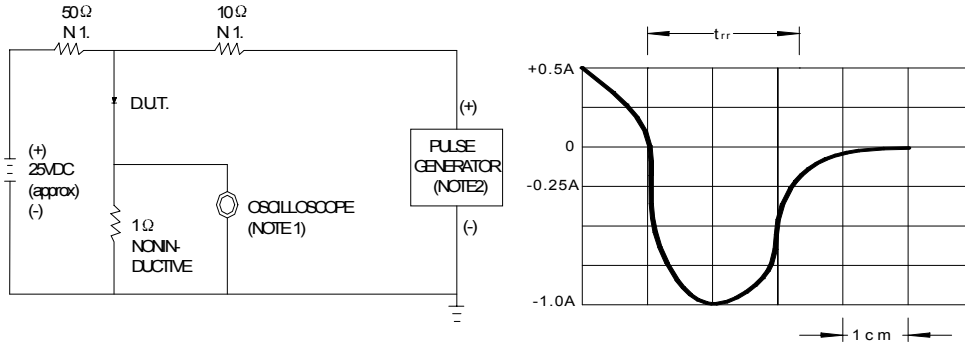
Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		ERB32 - 01	ERB32 - 02	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	100	200	V
Maximum RMS voltage	$V_{RMS}$	70	140	V
Maximum DC blocking voltage	$V_{DC}$	100	200	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	1.2		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	$I_{FSM}$	50.0		A
Maximum instantaneous forward voltage @ 1.2A	$V_F$	0.92		V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	$I_R$	5.0	50.0	$\mu A$
Maximum reverse recovery time (Note1)	$t_{rr}$	50		ns
Typical junction capacitance (Note2)	$C_J$	50		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50		$^\circ C/W$
Operating junction temperature range	$T_J$	- 55 ----- + 150		$^\circ C$
Storage temperature range	$T_{STG}$	- 55 ----- + 150		$^\circ C$

NOTE: 1. Measured with  $I_F=0.5A$ ,  $I_R=1A$ ,  $I_{rr}=0.25A$ .  
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
 3. Thermal resistance from junction to ambient.

**RATINGS AND CHARACTERISTIC CURVES ERB32-01 THRU ERB32-02**

**FIG.1-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**

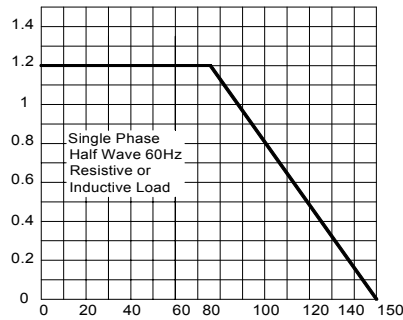


NOTES: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1MΩ. 22pF  
2. RISE TIME=10ns MAX. SOURCE IMPEDANCE=50Ω.

SET TIME BASE FOR 20/30 ns/cm

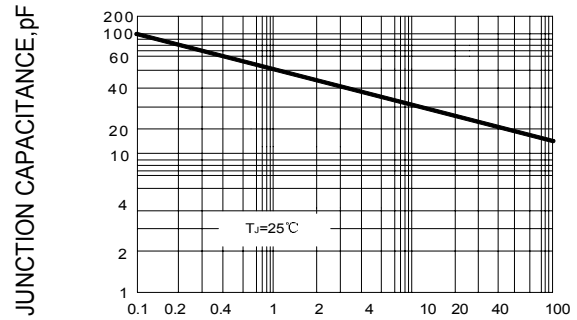
**FIG.2 -FORWARD DERATING CURVE**

AVERAGE FORWARD RECTIFIED CURRENT.  
AMPERES



AMBIENT TEMPERATURE. °C

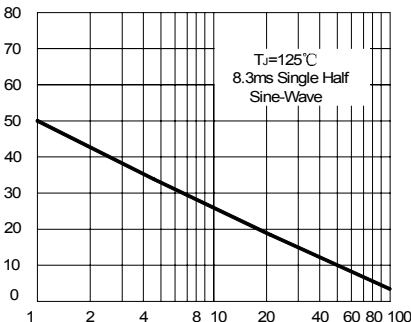
**FIG.3-TYPICAL JUNCTION CAPACITANCE**



REVERSE VOLTAGE, VOLTS

**FIG.4-PEAK FORWARD SURGE CURRENT**

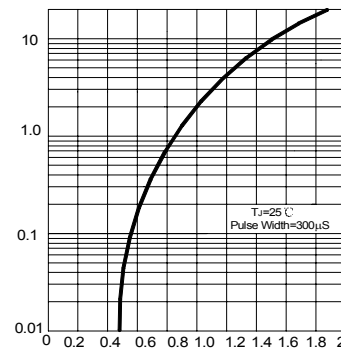
PEAK FORWARD SURGE CURRENT.  
AMPERES



NUMBER OF CYCLES AT 60HZ

**FIG.5 - TYPICAL FORWARD CHARACTERISTIC**

INSTANTANEOUS FORWARD CURRENT  
AMPERES



INSTANTANEOUS FORWARD VOLTAGE, VOLTS